

PMEG6010ETR

High-temperature 60 V, 1 A Schottky barrier rectifier

10 October 2012

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Average forward current: $I_{F(AV)} \leq 1$ A
- Reverse voltage: $V_R \leq 60$ V
- Low forward voltage
- High power capability due to clip-bonding technology
- Small and flat lead SMD plastic package
- AEC-Q101 qualified
- High temperature $T_j \leq 175$ °C

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
I_F	forward current	$T_{sp} = 165$ °C		-	-	1.4	A
$I_{F(AV)}$	average forward current	$\delta = 0.5$; $f = 20$ kHz; $T_{amb} \leq 140$ °C; square wave	[1]	-	-	1	A
		$\delta = 0.5$; $f = 20$ kHz; $T_{sp} \leq 170$ °C; square wave		-	-	1	A
V_R	reverse voltage	$T_j = 25$ °C		-	-	60	V
V_F	forward voltage	$I_F = 1$ A; $T_j = 25$ °C		-	460	530	mV
I_R	reverse current	$T_j = 25$ °C; $V_R = 60$ V; $t_p \leq 300$ μ s; $\delta \leq 0.02$; pulsed		-	30	60	μ A



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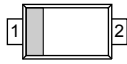



Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{rr}	reverse recovery time	$I_R = 0.5 \text{ A}$; $I_F = 0.5 \text{ A}$; $I_{R(\text{meas})} = 0.1 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$	-	4.4	-	ns

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al_2O_3 , standard footprint.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode ^[1]	 <p>SOD123W</p>	 sym001
2	A	anode		

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG6010ETR	SOD123W	plastic surface mounted package; 2 leads	SOD123W

4. Marking

Table 4. Marking codes

Type number	Marking code
PMEG6010ETR	EK

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V_R	reverse voltage	$T_j = 25 \text{ }^\circ\text{C}$	-	60	V	
I_F	forward current	$T_{sp} = 165 \text{ }^\circ\text{C}$	-	1.4	A	
$I_{F(\text{AV})}$	average forward current	$\delta = 0.5$; $f = 20 \text{ kHz}$; $T_{\text{amb}} \leq 140 \text{ }^\circ\text{C}$; square wave	[1]	-	1	A
		$\delta = 0.5$; $f = 20 \text{ kHz}$; $T_{sp} \leq 170 \text{ }^\circ\text{C}$; square wave		-	1	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8 \text{ ms}$; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$; square wave	-	50	A	

Symbol	Parameter	Conditions		Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	680	mW
			[3]	-	1150	mW
			[1]	-	2140	mW
T _j	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1][2]	-	-	220	K/W
			[1][3]	-	-	130	K/W
			[1][4]	-	-	70	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	18	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.

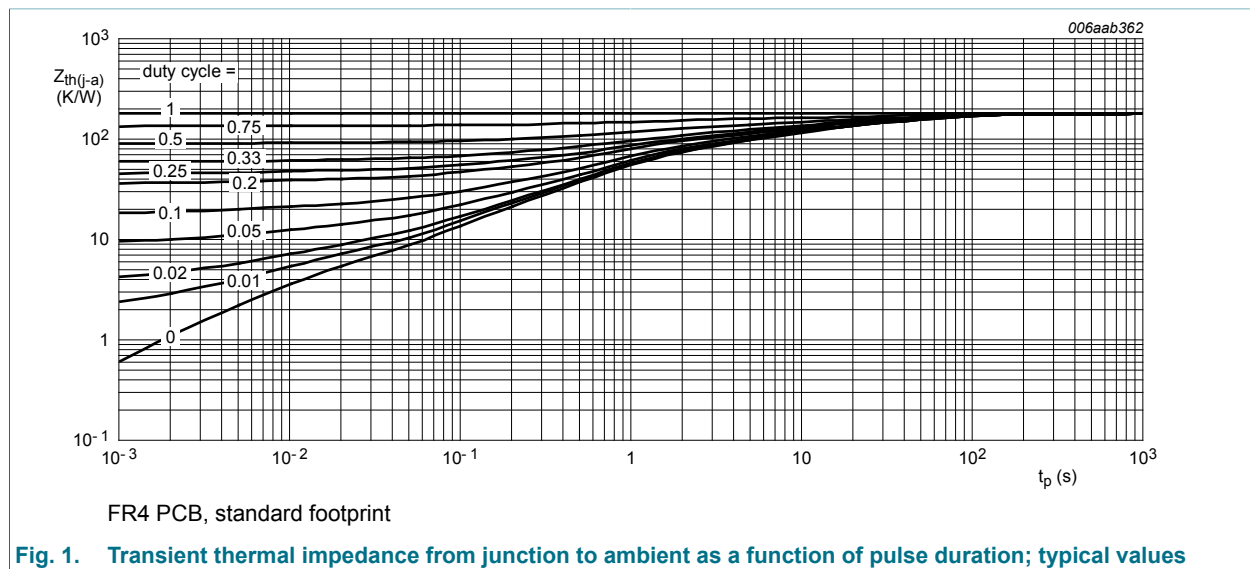


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

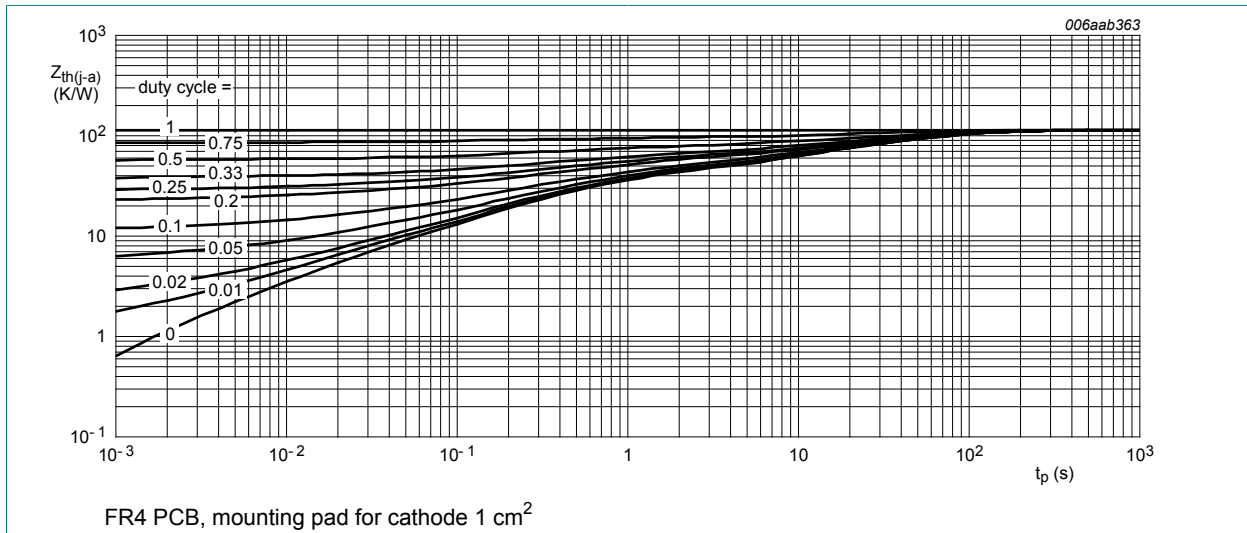


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

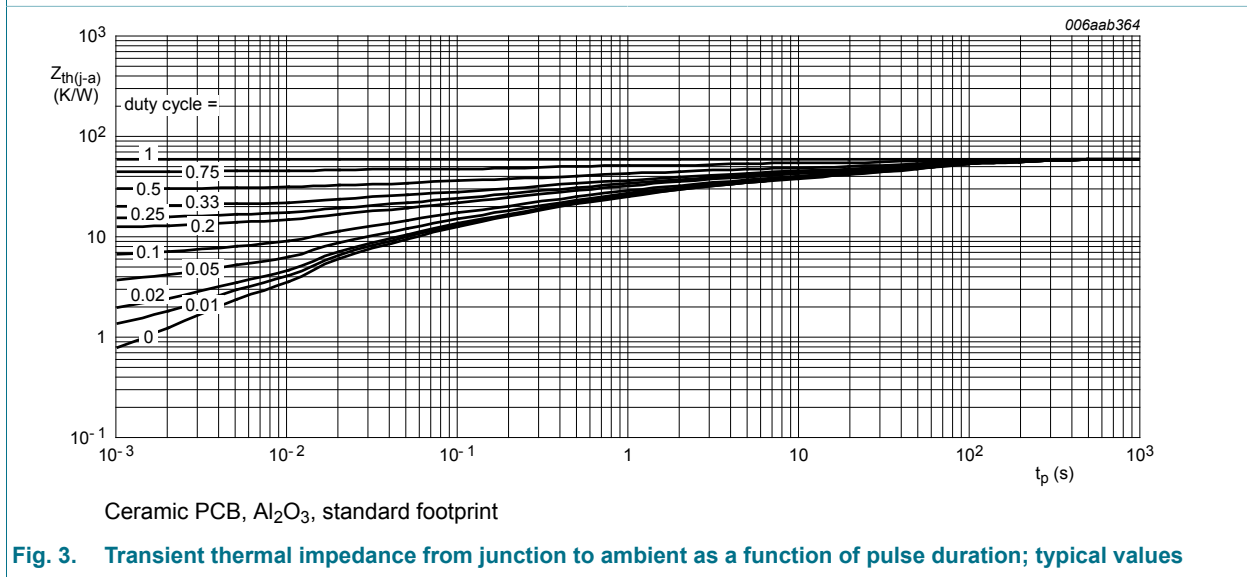


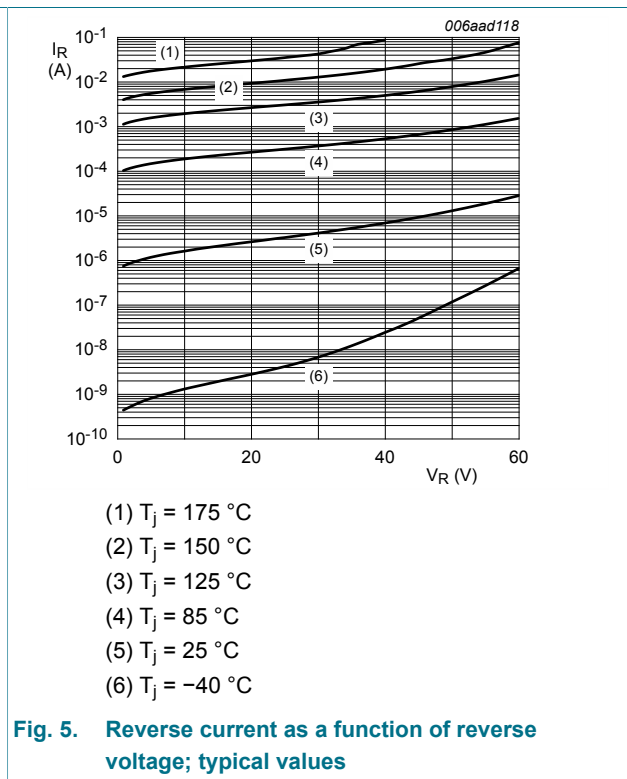
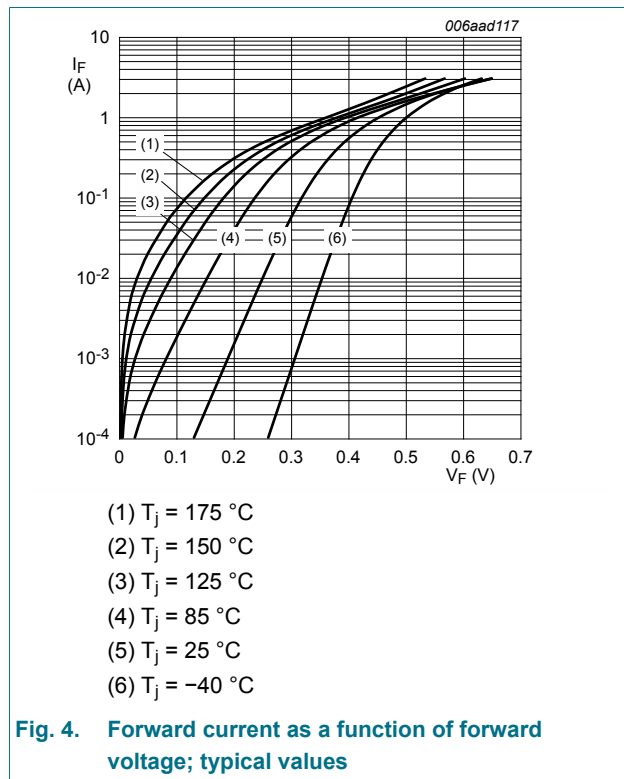
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _F	forward voltage	I _F = 0.1 A; T _j = 25 °C	-	320	370	mV
		I _F = 0.7 A; T _j = 25 °C	-	430	490	mV
		I _F = 1 A; T _j = 25 °C	-	460	530	mV
		I _F = 1 A; T _j = -40 °C	-	510	590	mV
		I _F = 1 A; T _j = 125 °C	-	400	480	mV
		I _F = 1 A; T _j = 150 °C	-	380	460	mV

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		$I_F = 1\text{ A}; T_j = 175\text{ }^\circ\text{C}$	-	365	450	mV
I_R	reverse current	$V_R = 5\text{ V}; T_j = 25\text{ }^\circ\text{C}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$; pulsed	-	1.2	-	μA
		$V_R = 10\text{ V}; T_j = 25\text{ }^\circ\text{C}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$; pulsed	-	1.7	-	μA
		$V_R = 60\text{ V}; T_j = 25\text{ }^\circ\text{C}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$; pulsed	-	30	60	μA
		$V_R = 60\text{ V}; T_j = -40\text{ }^\circ\text{C}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$; pulsed	-	0.6	10	μA
		$V_R = 60\text{ V}; T_j = 125\text{ }^\circ\text{C}; t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$; pulsed	-	14	50	mA
C_d	diode capacitance	$V_R = 1\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C}$	-	120	-	pF
		$V_R = 10\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C}$	-	40	-	pF
t_{rr}	reverse recovery time	$I_F = 0.5\text{ A}; I_R = 0.5\text{ A}; I_{R(\text{meas})} = 0.1\text{ A}; T_j = 25\text{ }^\circ\text{C}$	-	4.4	-	ns
V_{FRM}	peak forward recovery voltage	$I_F = 1\text{ A}; dI_F/dt = 40\text{ A}/\mu\text{s}; T_j = 25\text{ }^\circ\text{C}$	-	500	-	mV



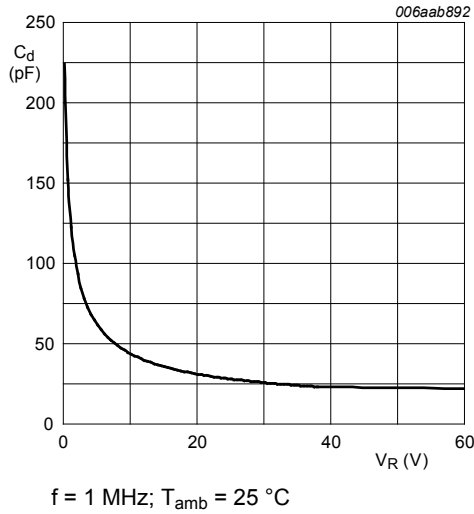


Fig. 6. Diode capacitance as a function of reverse voltage; typical values

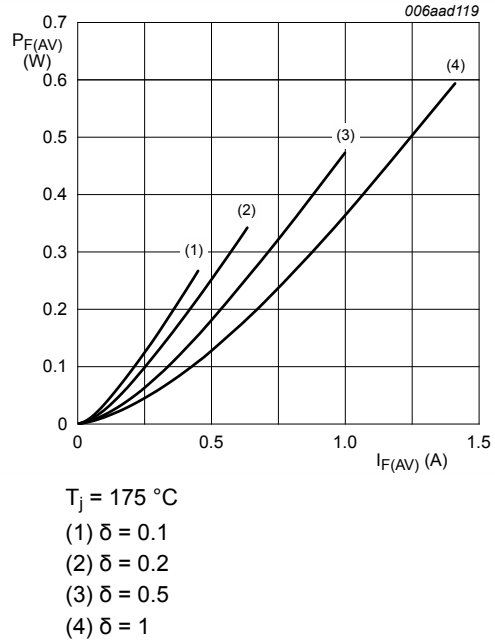


Fig. 7. Average forward power dissipation as a function of average forward current; typical values

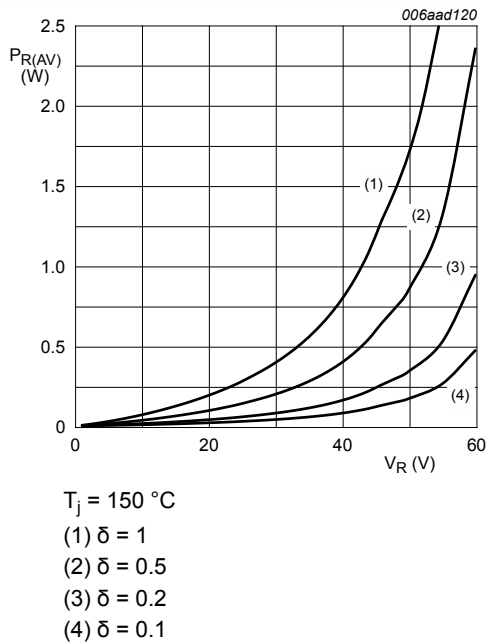


Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values

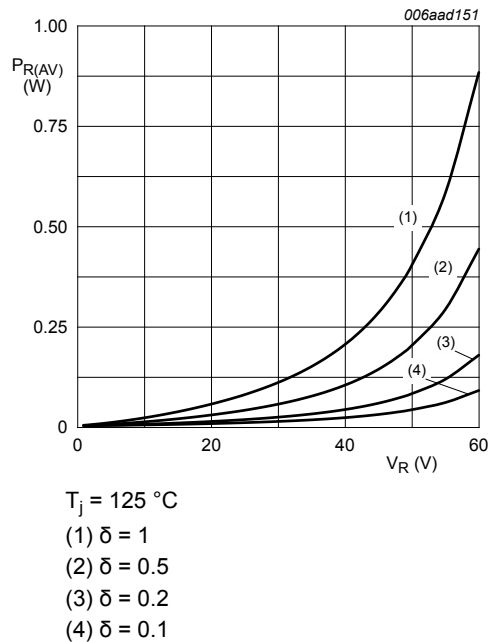


Fig. 9. Average reverse power dissipation as a function of reverse voltage; typical values

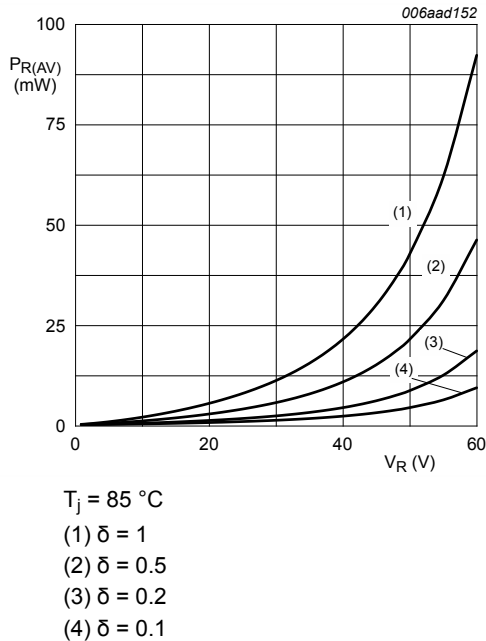


Fig. 10. Average reverse power dissipation as a function of reverse voltage; typical values

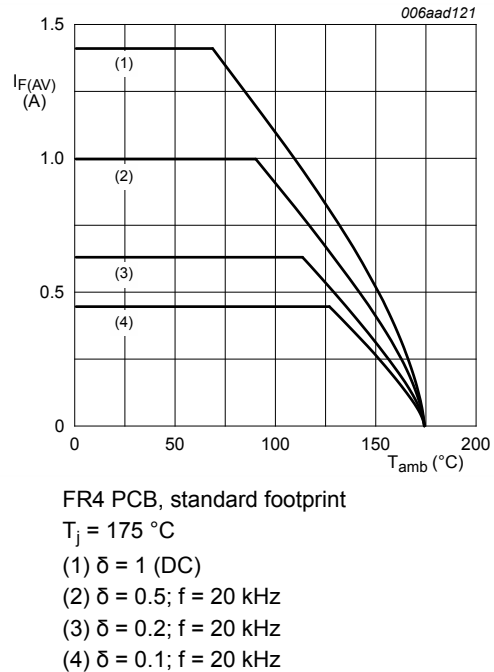


Fig. 11. Average forward current as a function of ambient temperature; typical values

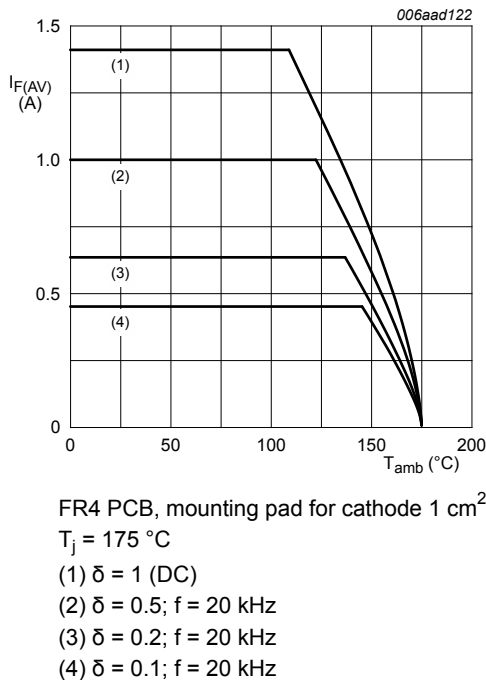


Fig. 12. Average forward current as a function of ambient temperature; typical values

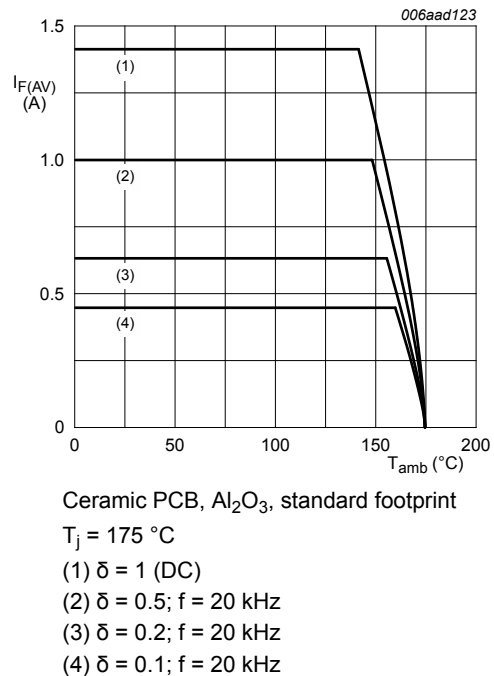
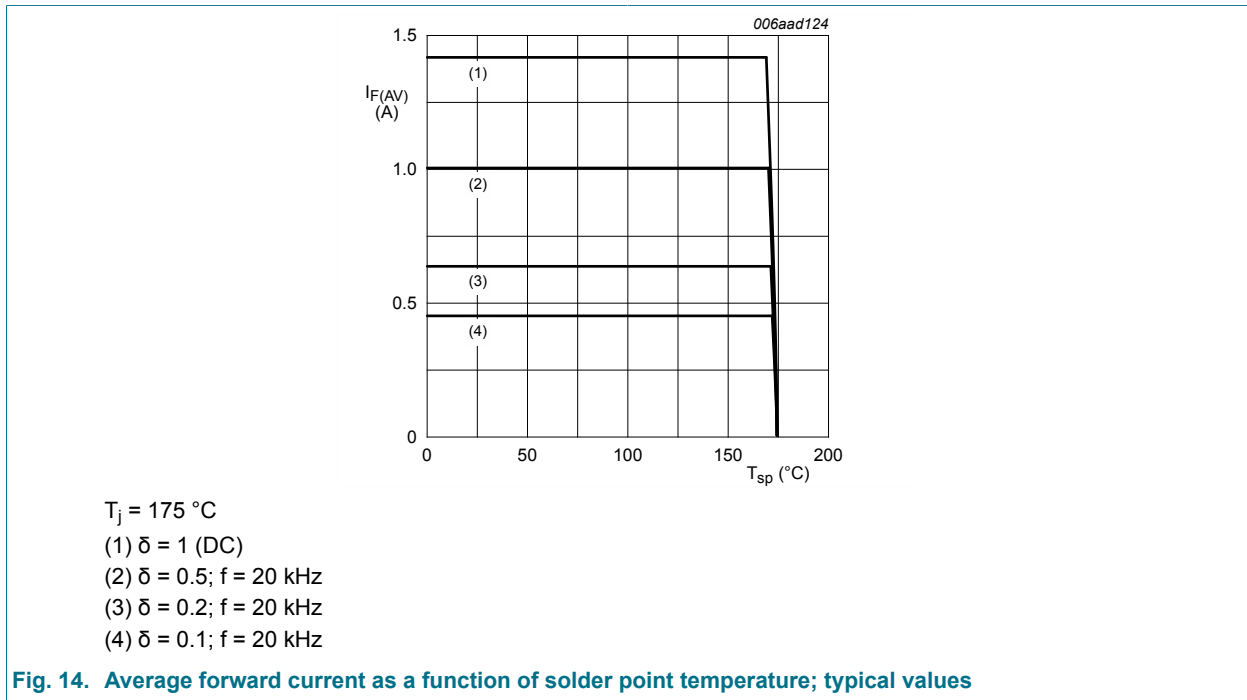
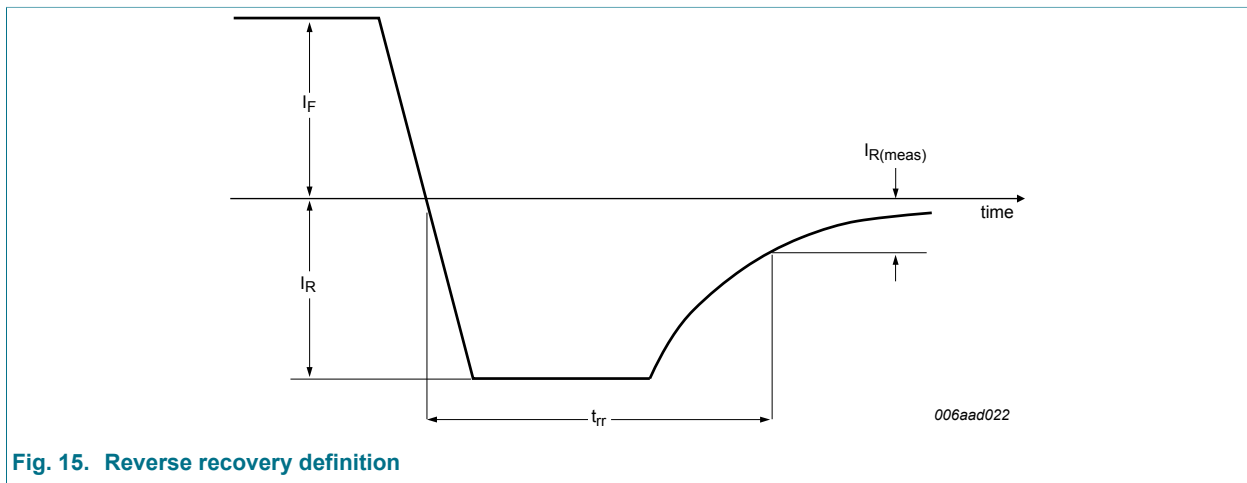


Fig. 13. Average forward current as a function of ambient temperature; typical values



8. Test information



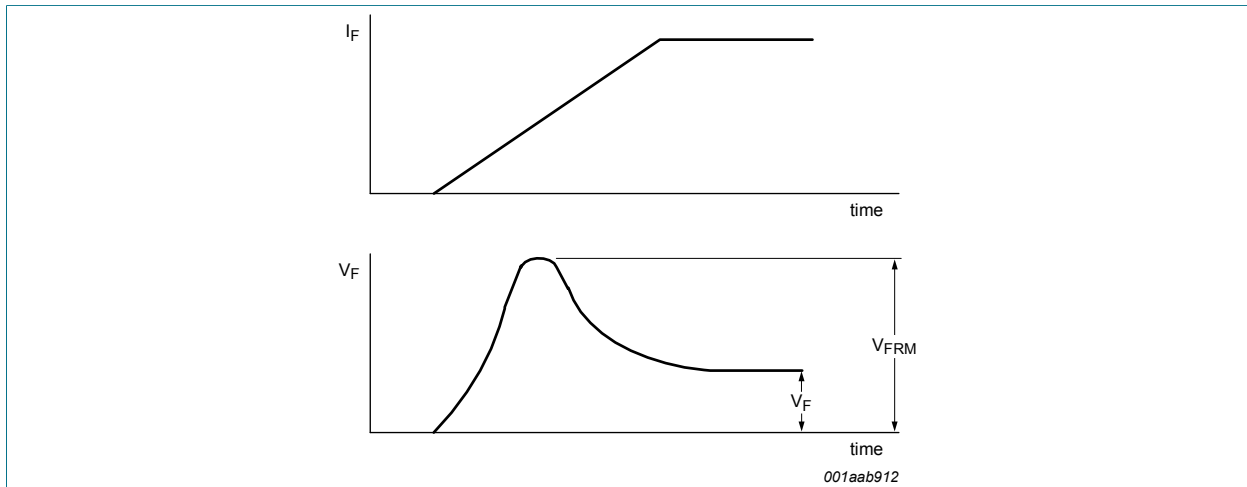


Fig. 16. Forward recovery definition

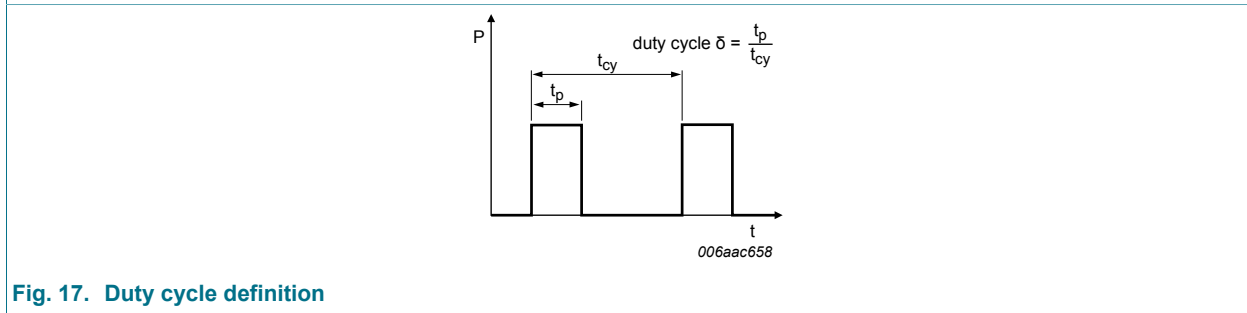


Fig. 17. Duty cycle definition

The current ratings for the typical waveforms are calculated according to the equations:
 $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline

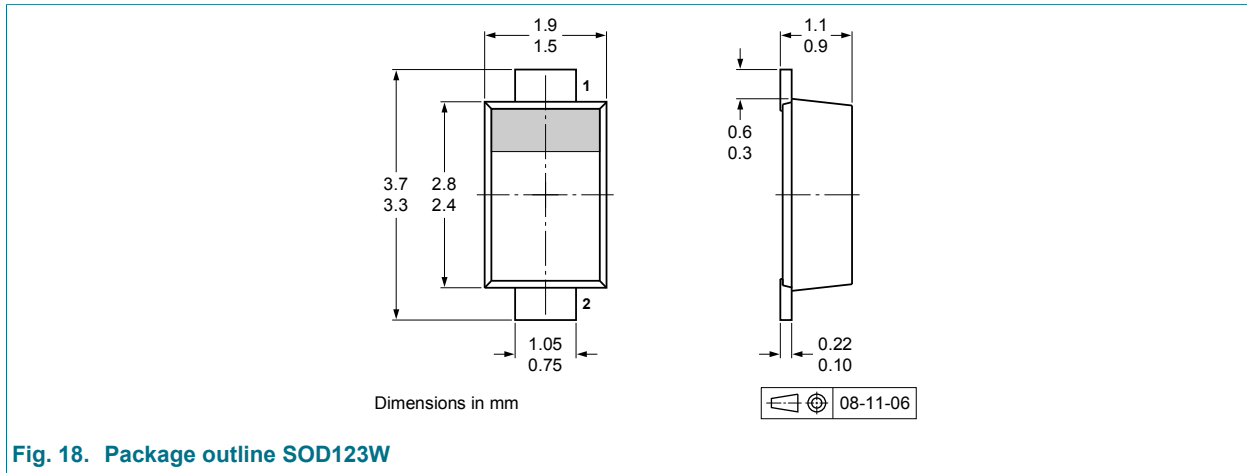


Fig. 18. Package outline SOD123W

10. Soldering

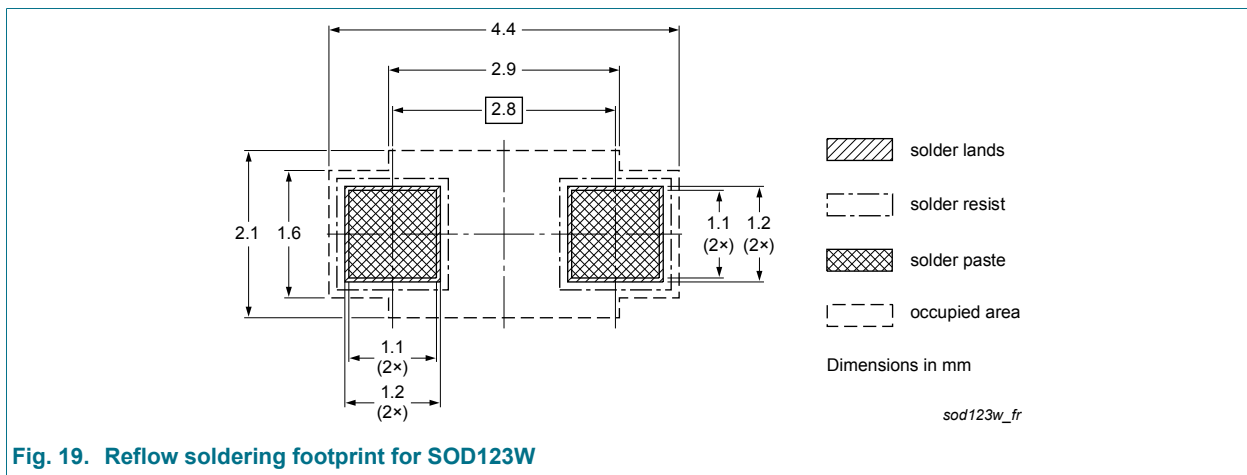


Fig. 19. Reflow soldering footprint for SOD123W

11. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG6010ETR v.1	20121010	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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13. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	2
6	Thermal characteristics	3
7	Characteristics	4
8	Test information	8
8.1	Quality information	
9	Package outline	10
10	Soldering	10
11	Revision history	10
12	Legal information	11
12.1	Data sheet status	11
12.2	Definitions	11
12.3	Disclaimers	11
12.4	Trademarks	12

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